

FEATURES

Controlled Baseline

- One Assembly/Test Site, One Fabrication Site

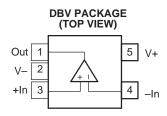
- **Extended Temperature Performance of** –55°C to 125°C
- Enhanced Diminishing Manufacturing Sources (DMS) Support
- **Enhanced Product-Change Notification** .
- Qualification Pedigree (1) •
- **Single-Supply Operation** .
- Rail-to-Rail Output (Within 3 mV) •
- Micro Power: $I_0 = 23 \mu A / Amplifier$
- Component qualification in accordance with JEDEC and (1) industry standards to ensure reliable operation over an extended temperature range. This includes, but is not limited to, Highly Accelerated Stress Test (HAST) or biased 85/85, temperature cycle, autoclave or unbiased HAST, electromigration, bond intermetallic life, and mold compound life. Such qualification testing should not be viewed as justifying use of this component beyond specified performance and environmental limits.

DESCRIPTION/ORDERING INFORMATION

- Micro-Size Packages
- Low Offset Voltage: 500 µV Typical
- Specified From $V_S = 2.3$ V to 5.5 V

APPLICATIONS

- **Battery-Powered Instruments**
- **Portable Devices**
- **High-Impedance Applications**
- **Photodiode Preamplifiers**
- Precision Integrators
- **Medical Instruments**
- **Test Equipment**



The OPA336 micro-power CMOS operational amplifier (MicroAmplifier™ series) is designed for battery-powered applications. The device operates on a single supply, with operation as low as 2.1 V. The output is rail to rail and swings to within 3 mV of the supplies with a 100-k Ω load. The common-mode range extends to the negative supply — ideal for single-supply applications.

In addition to small size and low quiescent current (23 µA/amplifier), the OPA336 features low offset voltage (500 µV typical), low input bias current (1 pA), and high open-loop gain (115 dB).

The device is packaged in the tiny DBV (SOT23-5) surface-mount package. It operates from -55°C to 125°C. A macromodel is available for download (at www.ti.com) for design analysis.

ORDERING INFORMATION

T _A	PACKAGE	ORDERABLE PART NUMBER	TOP-SIDE MARKING
–55°C to 125°C	DBV – SOT23-5	OPA336MDBVREP	OAYM

ELECTROSTATIC DISCHARGE SENSITIVITY

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. MicroAmplifier is a trademark of Texas Instruments.

OPA336-EP SINGLE-SUPPLY MICRO-POWER CMOS OPERATIONAL AMPLIFIER MicroAmplifier[™] SERIES sces658-JUNE 2006



Absolute Maximum Ratings⁽¹⁾

			MIN	MAX	UNIT
	Supply voltage			7.5	V
	Cignal input torminals	Voltage range ⁽²⁾	(V–) – 0.3	(V+) + 0.3	V
	Signal input terminals	Current ⁽²⁾		10	mA
	Output short circuit ⁽³⁾			Continuous	
T _A	Operating free-air tempera	ture range	-55	125	°C
T _{stg}	Storage temperature range	9	-55	125	°C
TJ	Junction temperature			150	°C
	Lead temperature (soldering	ng, 10 s)		300	°C
		Charged-Device Model (CDM)		1000	
	ESD rating	Human-Body Model (HBM)		500	V
		Machine Model (MM)		100	
θ_{JA}	Package thermal impedan	ce		200	°C/W

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) Input terminals are diode clamped to the power-supply rails. Input signals that can swing more than 0.3 V beyond the supply rails should be current limited to 10 mA or less.

(3) Short circuit to ground, one amplifier per package

OPA336-EP SINGLE-SUPPLY MICRO-POWER CMOS OPERATIONAL AMPLIFIER MicroAmplifier™ SERIES

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Electrical Characteristics

over recommended operating temperature range, V_S = 2.3 V to 5.5 V, T_A = 25°C, V_S = 5 V, R_L = 25 k Ω connected to V_S/2 (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Offset Vo	bltage	i					
	Input offset voltage				±500		
V _{OS}	Input offset voltage overtemperature ⁽¹⁾				μV		
	Input offset voltage vs power supply	V 00.04 55V		25	100		
PSRR	Overtemperature ⁽¹⁾	V _S = 2.3 V to 5.5 V			150	μV/V	
	Channel separation, dc			0.1			
Input Bia	is Current	I					
	Input bias current			±1	±10		
I _B	Overtemperature ⁽¹⁾				±200	рА	
I _{OS}	Input offset current			±1	±60	pА	
Noise							
	Input voltage noise	f = 0.1 Hz to 10 Hz		3		μVp-p	
e _n	Input voltage noise density	f = 1 kHz		40		nV/√ Hz	
i _n	Current noise density	f = 1 kHz		30		fA/√Hz	
Input Vol	Itage Range	I					
V _{CM}	Common-mode voltage range		-0.2		(V+) – 1	V	
	Common-mode rejection ratio		76	86			
CMRR Overtemperature ⁽¹⁾		-0.2 V < V _{CM} < (V+) - 1 V	72			dB	
Input Imp	pedance						
	Differential input impedance			10 ¹³ 2		ΩpF	
	Common mode input impedance			10 ¹³ 4		Ω pF	
Open-Lo	op Gain	I					
		$R_L = 25 k\Omega$, 100 mV < V _O < (V+) – 100 mV	90				
٨	Open-loop voltage gain	$R_L = 5 k\Omega$, 500 mV < V _O < (V+) - 500 mV	90			dD	
A _{OL}	Overtemperature ⁽¹⁾	$R_L = 25 k\Omega,$ 100 mV < V _O < (V+) – 100 mV	82			dB	
	Ovenemperature	$R_L = 5 \text{ k}\Omega,$ 500 mV < V _O < (V+) - 500 mV	89				
Frequenc	cy Response						
GBW	Gain-bandwidth product	V _S = 5 V, G = 1		100		kHz	
SR	Slew rate	V _S = 5 V, G = 1		0.03		V/µs	
	Overload recovery time	$V_{IN} \times G = V_S$		100		μs	

(1) Limits apply over the specified temperature range, $T_A = -55^{\circ}C$ to 125°C.

OPA336-EP SINGLE-SUPPLY MICRO-POWER CMOS OPERATIONAL AMPLIFIER MicroAmplifier[™] SERIES



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Electrical Characteristics (continued)

over recommended operating temperature range, V_S = 2.3 V to 5.5 V, T_A = 25°C, V_S = 5 V, R_L = 25 k Ω connected to V_S/2 (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Output						
		$R_L = 100 \text{ k}\Omega, A_{OL} \ge 70 \text{ dB}$		3		
Voltage output swing from rail ⁽²⁾		$R_L = 25 \text{ k}\Omega, \text{ A}_{OL} \ge 90 \text{ dB}$		20	100	mV
		$R_L = 5 \text{ k}\Omega, A_{OL} \ge 90 \text{ dB}$		70	500	
	Que et e man e materia (3)	$R_L = 25 \text{ k}\Omega, A_{OL} \ge 82 \text{ dB}$			100	
	Overtemperature ⁽³⁾	$R_L = 5 \text{ k}\Omega, \text{ A}_{OL} \ge 89 \text{ dB}$			500	mV
I _{SC}	Short-circuit current			±5		mA
C _{LOAD}	Capacitive load drive ⁽⁴⁾					
Power S	upply					
Vs	Specified voltage range		2.3		5.5	V
	Minimum operating voltage			2.1		V
Quiescent current (per amplifier)		1 0		23	35	^
IQ	Overtemperature ⁽³⁾	$I_{O} = 0$			38	μA

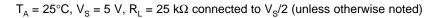
(2) Output voltage swings are measured between the output and positive and negative power-supply rails. (3) Limits apply over the specified temperature range, $T_A = -55^{\circ}C$ to 125°C.

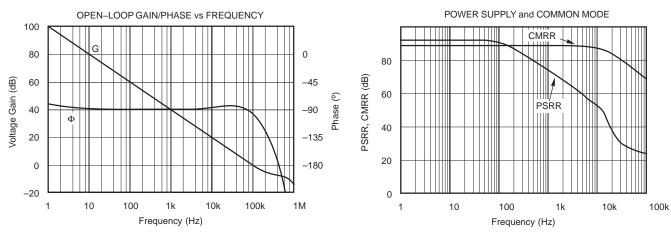
(4) See Capacitive Load and Stability section

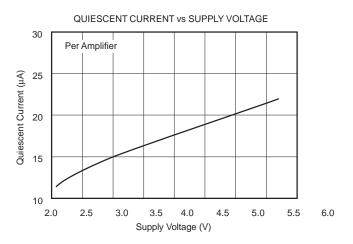
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TYPICAL CHARACTERISTICS





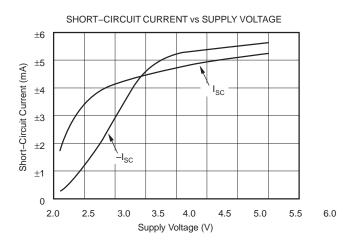


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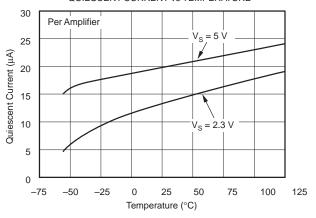
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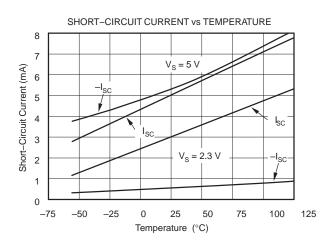
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TRUMENTS www.ti.com



QUIESCENT CURRENT vs TEMPERATURE



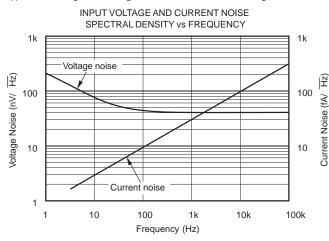


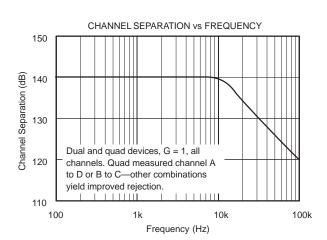
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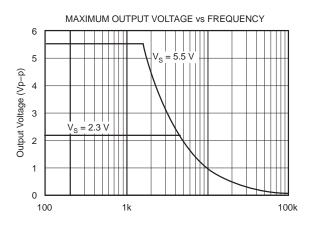


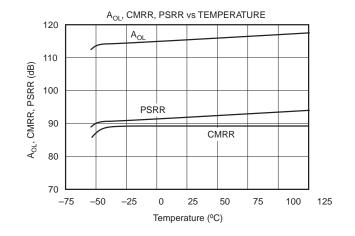
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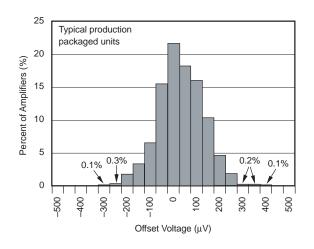
 $T_A = 25^{\circ}C$, $V_S = 5 V$, $R_L = 25 k\Omega$ connected to $V_S/2$ (unless otherwise noted)

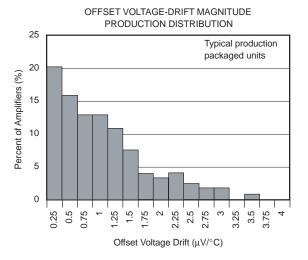












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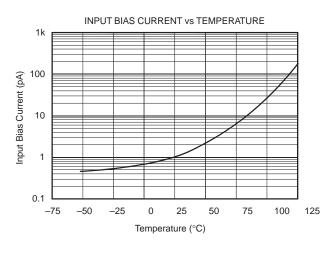


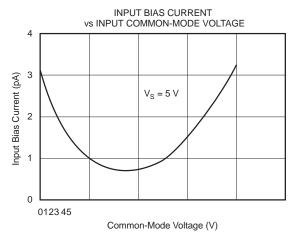
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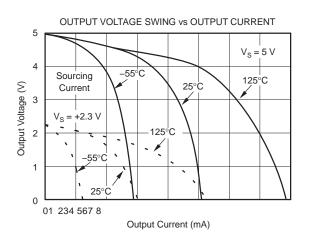
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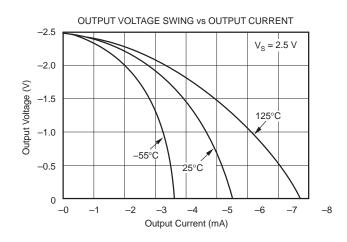
TYPICAL CHARACTERISTICS (continued)

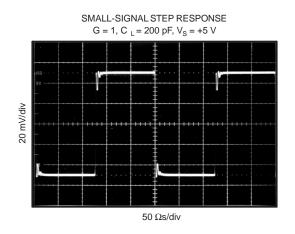
$T_A = 25^{\circ}C$, $V_S = 5$ V, $R_L = 25$ k Ω connected to $V_S/2$ (unless otherwise noted)

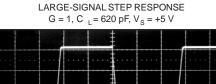


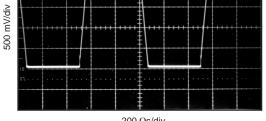












200 Ωs/div



APPLICATION INFORMATION

The OPA336 operational amplifier is fabricated with a state-of-the-art 0.6-micron CMOS process. The device is unity-gain stable and suitable for a wide range of general-purpose applications. Power-supply pins should be bypassed with 0.01- μ F ceramic capacitors. The OPA336 is protected against reverse battery voltages.

Operating Voltage

The OPA336 can operate from a 2.1-V to 5.5-V single supply voltage, with excellent performance. Most behavior remains unchanged throughout the full operating voltage range. Parameters that vary significantly with operating voltage are shown in the typical characteristics. The OPA336 is fully specified for operation from 2.3 V to 5.5 V; a single limit applies over the supply range. In addition, many parameters are ensured over the specified temperature range, -55° C to 125° C.

Input Voltage

The input common-mode range of the OPA336 extends from (V-) - 0.2 V to (V+) - 1 V. For normal operation, inputs should be limited to this range. The absolute maximum input voltage is 300 mV beyond the supplies. Thus, inputs greater than the input common-mode range, but less than maximum input voltage, while not valid, will not cause any damage to the operational amplifier. Furthermore, the inputs may go beyond the power supplies without phase inversion (see Figure 1), unlike some other operational amplifiers.

Normally, input bias current is approximately 1 pA. However, input voltages exceeding the power supplies can cause excessive current to flow in or out of the input pins. Momentary voltages greater than the power supply can be tolerated, as long as the current on the input pins is limited to 10 mA. This is easily accomplished with an input resistor (see Figure 2).

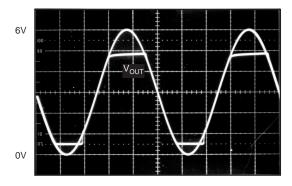


Figure 1. No Phase Inversion With Inputs Greater Than Power-Supply Voltage

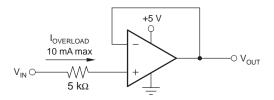


Figure 2. Input Current Protection for Voltages Exceeding Power-Supply Voltage

APPLICATION INFORMATION (CONTINUED)

Capacitive Load and Stability

The OPA336 can drive a wide range of capacitive loads. However, all operational amplifiers, under certain conditions, may become unstable. Operational amplifier configuration, gain, and load value are just a few of the factors to consider when determining stability.

When properly configured, the OPA336 drives approximately 10,000 pF. An operational amplifier in unity-gain configuration is the most vulnerable to capacitive load. The capacitive load reacts with the operational amplifier output resistance along with any additional load resistance to create a pole in the response, which degrades the phase margin. In unity gain, the OPA336 performs well with a pure capacitive load, up to about 300 pF. Increasing gain enhances the amplifier's ability to drive loads beyond this level.

One method of improving capacitive load drive in the unity-gain configuration is to insert a 50- Ω to 100- Ω resistor inside the feedback loop (see Figure 3). This reduces ringing with large capacitive loads, while maintaining direct current (DC) accuracy. For example, with R_L = 25 k Ω , OPA336 performs well with capacitive loads in excess of 1000 pF (see Figure 4). Without the OPA336 R_S, capacitive load drive typically is 350 pF for these conditions (see Figure 5).

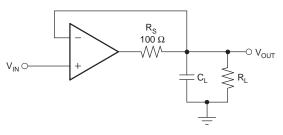


Figure 3. Series Resistor in Unity-Gain Configuration Improves Capacitive Load Drive

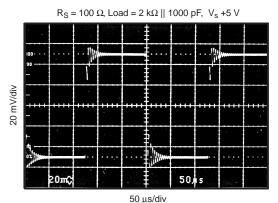


Figure 4. Small-Signal Step Response Using Series Resistor to Improve Capacitive Load Drive



APPLICATION INFORMATION (CONTINUED)

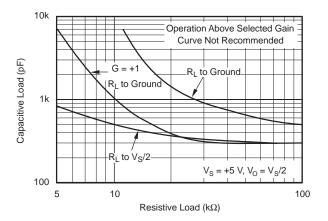


Figure 5. Stability — Capacitive Load vs Resistive Load

Alternatively, the resistor may be connected in series with the output outside of the feedback loop. However, if there is a resistive load parallel to the capacitive load, it and the series resistor create a voltage divider. This introduces a DC error at the output; however, this error may be insignificant. For instance, with $R_L = 100 \text{ k}\Omega$ and $R_S = 100 \Omega$, there is only about a 0.1% error at the output.

Figure 5 shows the recommended operating regions for the OPA336. Decreasing the load resistance generally improves capacitive load drive. Figure 5 also shows how stability differs, depending on where the resistive load is connected. With G = 1 and $R_L = 10 \text{ k}\Omega$ connected to $V_S/2$, the OPA336 typically can drive 500 pF. Connecting the same load to ground improves capacitive load drive to 1000 pF.



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
						(4)	(5)		
OPA336MDBVREP	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-55 to 125	OAYM
V62/06641-01XE	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-55 to 125	OAYM

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF OPA336-EP :

Catalog : OPA336



NOTE: Qualified Version Definitions:

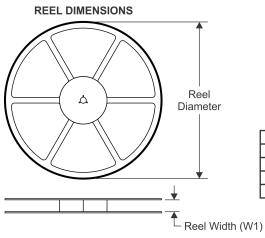
Catalog - TI's standard catalog product

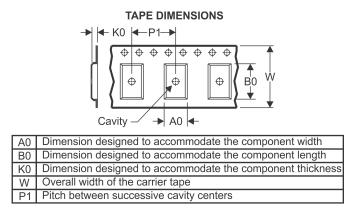
PACKAGE MATERIALS INFORMATION

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Texas Instruments

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



1	*All dimensions are nominal												
	Device	•	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	OPA336MDBVREP	SOT-23	DBV	5	3000	179.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

5-Jan-2021



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
OPA336MDBVREP	SOT-23	DBV	5	3000	213.0	191.0	35.0

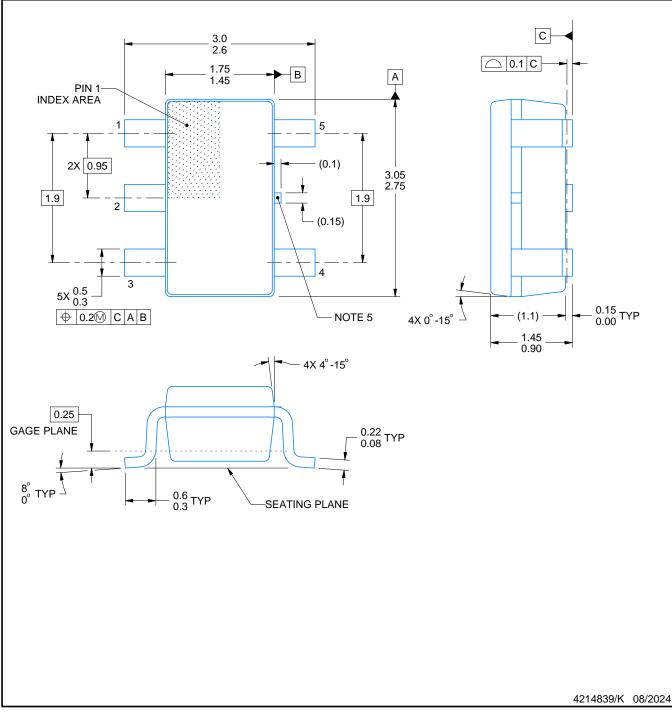
DBV0005A



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.

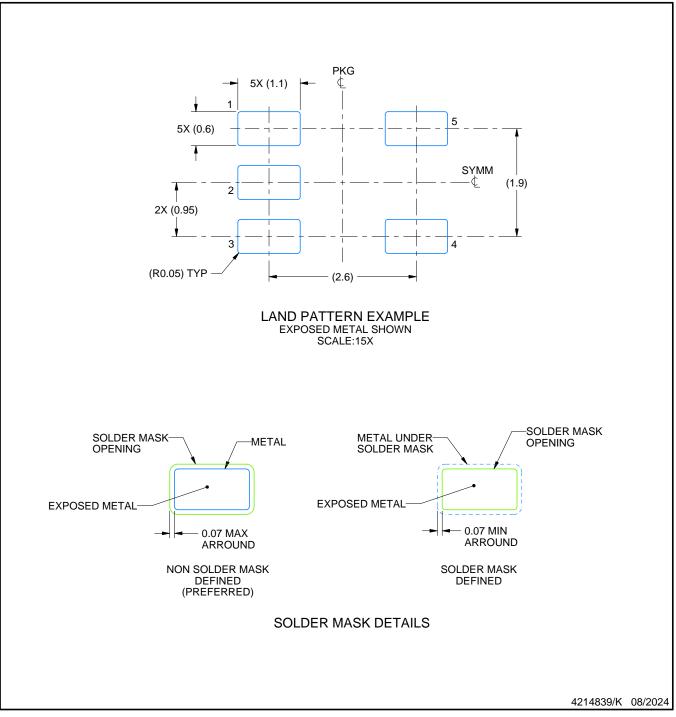


DBV0005A

EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

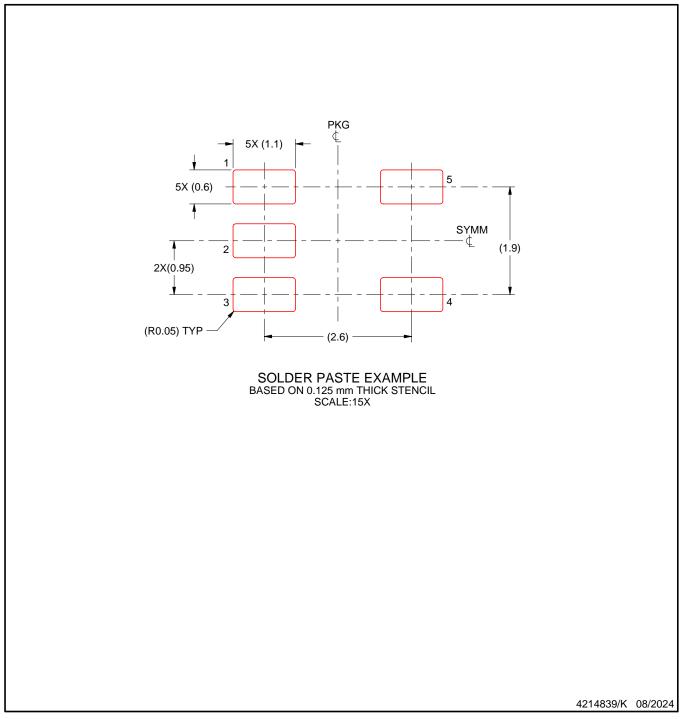


DBV0005A

EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

9. Board assembly site may have different recommendations for stencil design.



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